DATA SHEET



BIPOLAR DIGITAL INTEGRATED CIRCUIT $\mu PB1513TU$

13 GHz INPUT DIVIDE BY 4 PRESCALER IC FOR SATELLITE COMMUNICATIONS

DESCRIPTION

The μ PB1513TU is a silicon germanium (SiGe) monolithic integrated circuit designed as a divide by 4 prescaler IC for satellite communications and point-to-point/multi-point radios.

The package is 8-pin lead-less minimold suitable for surface mount.

This IC is manufactured using our 50 GHz fmax UHS2 (Ultra High Speed Process) SiGe bipolar process.

FEATURES

• Operating frequency : fin = 5 to 13 GHz

Low current consumption : Icc = 48 mA @ Vcc = 5.0 V
 High-density surface mounting : 8-pin lead-less minimold
 Supply voltage : Vcc = 4.5 to 5.5 V

• Division ratio : 4

APPLICATIONS

· Point-to-point/Multi-point radios

VSAT radios

ORDERING INFORMATION

Part Number	Order Number	Package	Marking	Supplying Form
μPB1513TU-E2	μPB1513TU-E2-A	8-pin lead-less minimold (Pb-Free) Note	1513	 8 mm wide embossed taping Pin 5, 6, 7, 8 indicates pull-out direction of tape Qty 5 kpcs/reel

Note With regards to terminal solder (the solder contains lead) plated products (conventionally plated), contact your nearby sales office.

Remark To order evaluation samples, contact your nearby sales office.

Part number for sample order: μ PB1513TU

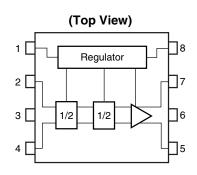
Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

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Not all devices/types available in every country. Please check with local NEC Compound Semiconductor Devices representative for availability and additional information.

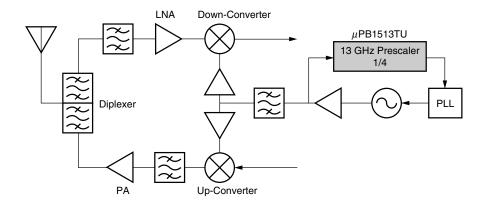
Document No. PU10540EJ02V0DS (2nd edition) Date Published March 2005 CP(K) Printed in Japan The mark ★ shows major revised points.

INTERNAL BLOCK DIAGRAM AND PIN CONNECTIONS



Pin No.	Pin Name		
1	Vcc1		
2	IN		
3	GND		
4	ĪN		
5	OUT		
6	GND		
7	OUT		
8	Vcc2		

SYSTEM APPLICATION EXAMPLE





PIN EXPLANATION

Pin No.	Pin Name	Applied Voltage (V)	Function and Applications
1	Vcc1	5	Power supply pin.
			This pin must be equipped with bypass capacitor (example : 100 pF and 10 nF) to minimize ground impedance.
2	IN	-	Signal input pin.
			This pin should be coupled to signal source with capasitor (example : 100 pF) for DC cut.
3	GND	0	Ground pin.
			Ground pattern on the board should be formed as widely as possible to minimize ground impedance.
4	ĪN	-	Signal input bypass pin.
			This pin must be equipped with bypass capacitor (example : 100 pF) to minimize ground impedance.
5	OUT	_	Divided frequency output pin.
			This pin shoud be coupled to load device with capasitor (example : 100 pF) for DC cut.
6	GND	0	Ground pin.
			Ground pattern on the board should be formed as widely as possible to minimize ground impedance.
7	OUT	_	Divided frequency output pin.
			This pin should be coupled to load device with capasitor (example : 100 pF) for DC cut.
8	Vcc2	5	Power supply pin.
			This pin must be equipped with bypass capacitor (example : 100 pF and 10 nF) to minimize ground impedance.



ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Test Conditions	Ratings	Unit
Supply Voltage	Vcc	T _A = +25°C	6	V
Total Power Dissipation	P□	$T_A = +85^{\circ}C$ Note	867	mW
Thermal Resistance (junction to ground paddle)	Rth(j-c)	T _A = +85°C Note	75	°C/W
Operating Ambient Temperature	TA		-40 to +85	°C
Storage Temperature	Tstg		-55 to +150	°C

Note Mounted on $33 \times 21 \times 0.4$ mm polyimide PCB, with copper patterning on both sides.

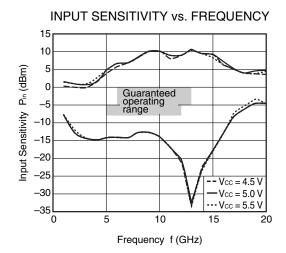
RECOMMENDED OPERATING RANGE

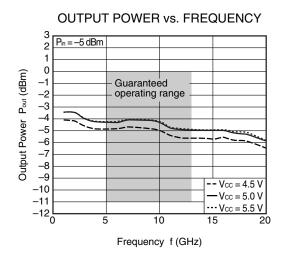
Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Supply Voltage	Vcc	4.5	5.0	5.5	٧
Operating Ambient Temperature	Та	-40	+25	+85	°C

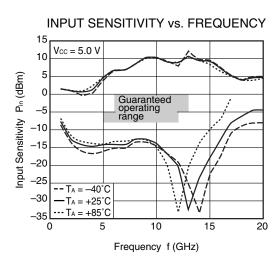
ELECTRICAL CHARACTERISTICS (Vcc = 4.5 to 5.5 V, TA = -40 to +85°C, Zs = ZL = 50 Ω)

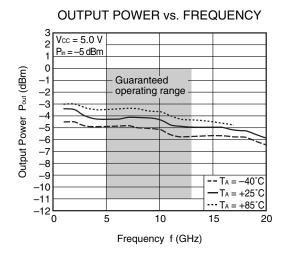
Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Circuit Current	Icc	No Signals	-	48	75	mA
Input Sensitivity	Pin1	fin = 5 to 6 GHz	-8	-	-5	dBm
	Pin2	fin = 6 to 12 GHz	-8	-	0	dBm
	Pin3	fin = 12 to 13 GHz	-5	-	0	dBm
Output Power	Pout	$f_{\text{in}} = 5 \text{ to } 13 \text{ GHz}, \text{ single ended},$ $P_{\text{in}} = -5 \text{ dBm}$	-11	-4	2	dBm

TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)

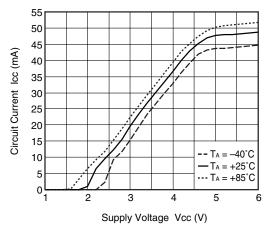








★ CURCUIT CURRENT vs. SUPPLY VOLTAGE



Remark The graphs indicate nominal characteristics.

NEC μ PB1513TU

S₁₁

ANG

170.5

139.7

112.0

90.6

71.2

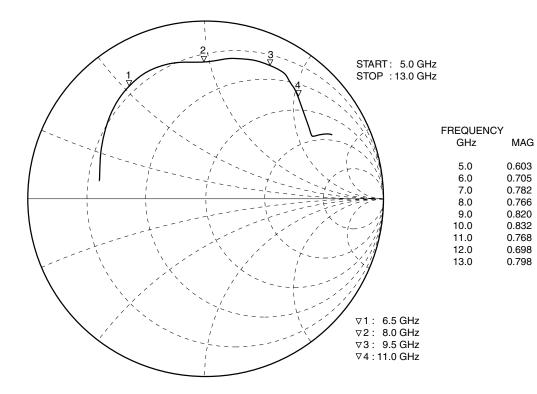
57.9

46.3

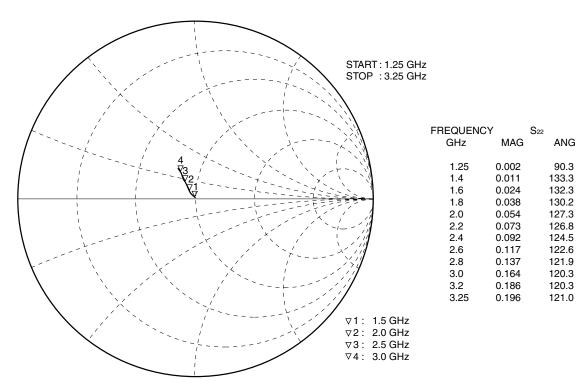
32.2

26.6

★ S-PARAMETERS (TA = +25°C, Vcc = 5.0 V) S₁₁-FREQUENCY



S22-FREQUENCY

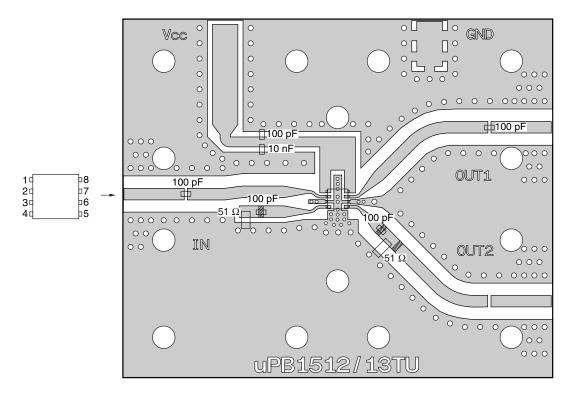


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MEASUREMENT CIRCUIT 100 pF 10 nF Power Supply Vcc1 Vcc2 100 pF 100 pF OUT GND GND **§** 50 Ω ĪN OUT Spectrum Analyzer Signal Generator 100 pF 51 Ω

The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

ILLUSTRATION OF THE MEASUREMENT CIRCUIT ASSEMBLED ON EVALUATION BOARD



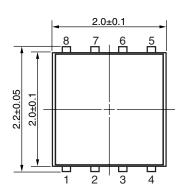
Remarks 1. $33 \times 21 \times 0.4$ mm double-sided copper-clad polyimide PCB

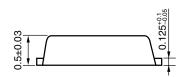
- 2. Back side: GND pattern
- 3. Solder plated on pattern
- 4. represents cutout
- 5. oO: Through holes

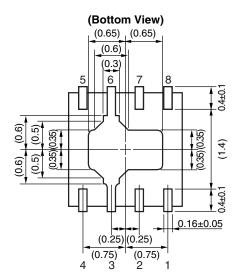
PACKAGE DIMENSIONS

8-PIN LEAD-LESS MINIMOLD (UNIT: mm)

(Top View)







NOTES ON CORRECT USE

- (1) Observe precautions for handling because of electro-static sensitive devices.
- (2) Form a ground pattern as widely as possible to minimize ground impedance (to prevent undesired oscillation).
- (3) Keep the track length of the ground terminals as short as possible.
- (4) Bypass capacitance must be attached to Vcc line.
- (5) Exposed heatsink at bottom on package must be soldered to PCB RF/DC ground.

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions	Condition Symbol	
Infrared Reflow	Peak temperature (package surface temperature) Time at peak temperature Time at temperature of 220°C or higher Preheating time at 120 to 180°C Maximum number of reflow processes Maximum chlorine content of rosin flux (% mass)	: 260°C or below : 10 seconds or less : 60 seconds or less : 120±30 seconds : 3 times : 0.2%(Wt.) or below	IR260
Wave Soldering	Peak temperature (molten solder temperature) Time at peak temperature Preheating temperature (package surface temperature) Maximum number of flow processes Maximum chlorine content of rosin flux (% mass)	: 260°C or below : 10 seconds or less	WS260
Partial Heating	Peak temperature (terminal temperature) Soldering time (per side of device) Maximum chlorine content of rosin flux (% mass)	: 350°C or below : 3 seconds or less : 0.2%(Wt.) or below	HS350

Caution Do not use different soldering methods together (except for partial heating).

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M8E 00.4-0110

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